Schottky Barrier Rectifier DST860S, 8A, 60V, TO-277B, Single

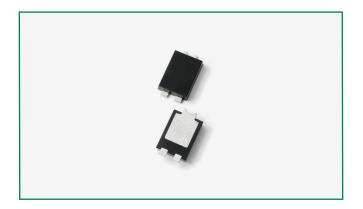
DST860S



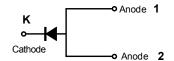








Pin out



Description

Littelfuse DST series Ultra Low V_F Schottky Barrier Rectifier is designed to meet the general requirements of commercial and industry applications by providing high temperature, low leakage and lower V_E products.

It is suitable for high frequency switching mode power supply, free-wheeling diodes and polarity protection diodes.

Features

- Ultra low forward voltage
- High frequency operation
- MSL: Level 1 unlimited
- High junction temperature capability
- Trench MOS Schottky technology
- Single die in TO-277B Package
- Pb-free E3 means 2nd level interconnect is Pb-free and the terminal finish material is tin(Sn) (IPC/ JEDEC J-STD-609A.01)

Applications

- Switching mode power supply
- DC/DC converters
- Free-Wheeling diodes
- Polarity Protection Diodes

Maximum Ratings

Parameters	Symbol	Test Conditions	Max	Unit
Peak Inverse Voltage	V _{RWM}	-	60	V
Average Forward Current	I _{F(AV)}	50% duty cycle @T _L = 125 °C rectangular wave form	8	А
Peak One Cycle Non-Repetitive Surge Current	I _{FSM}	8.3 ms, half Sine pulse	140	А

Electrical Characteristics

Parameters	Symbol	Test Conditions	Тур	Max	Unit
	\/	@4A, Pulse, T _J = 25 °C	0.42	-	
Forward Voltage Drop*	V _{F1}	@8A, Pulse, T _J = 25 °C	0.50	0.61	V
	\/	@4A, Pulse, T _J = 125 °C	0.34	-	V
	V _{F2}	@8A, Pulse, T _J = 125 °C	0.44	0.55	
Reverse Current*	I _{R1}	$@V_R = rated V_{R,} T_J = 25 ^{\circ}C$	0.02	0.6	mA
neverse Current	I _{R2}	$@V_R = rated V_{R,} T_J = 125 °C$	10	25	
Junction Capacitance	C _T	$@V_{B} = 5V, T_{C} = 25 \text{ °C}, f_{SIG} = 1MHz$	502	-	pF

^{*} Pulse Width < 300µs, Duty Cycle <2%

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Thermal-Mechanical Specifications

Parameters	Symbol	Test Conditions	Max	Unit
Junction Temperature	T _J		-55 to +150	°C
Storage Temperature	T _{stg}		-55 to +150	°C
Maximum Thermal Resistance Junction to Ambient	R _{thJA}	DC operation	75	°C/W
Maximum Thermal Resistance Junction to Lead	R _{thJL}		4	°C/W
Approximate Weight	wt		0.08	g
Case Style	TO-277B			

Figure 1: Typical Forward Characteristics

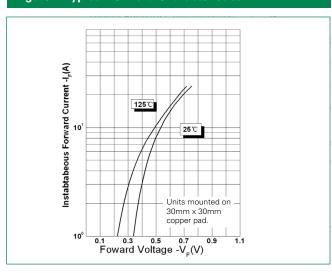


Figure 2: Typical Reverse Characteristics

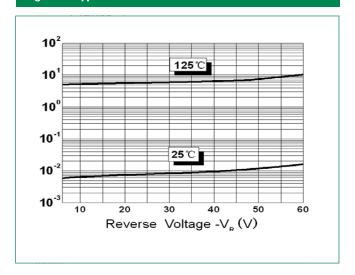
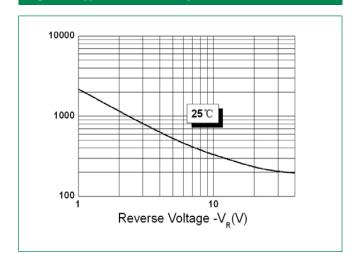
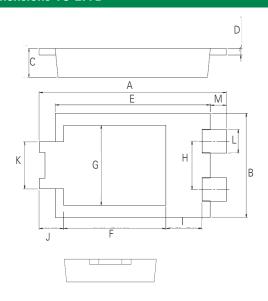


Figure 3: Typical Junction Capacitance



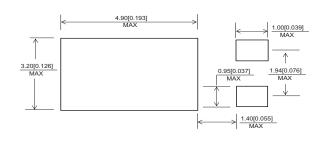
Schottky Barrier Rectifier DST860S, 8A, 60V, TO-277B, Single

Dimensions-TO-277B

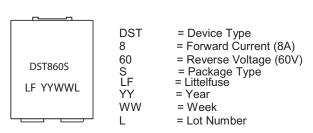


Symbol		Millimeters			
Зуптьог	Min	Тур	Max		
Α	6.30	6.50	6.70		
В	3.88	3.98	4.08		
С	0.95	1.10	1.25		
D	0.20	0.25	0.30		
E	5.28	5.38	5.48		
F	3.40	3.55	3.70		
G	2.90	3.05	3.20		
Н	1.74	1.84	1.94		
1	1.10	1.25	1.40		
J	-	0.85	-		
K	1.70	1.80	1.90		
L	0.85	0.90	0.95		
M	-	0.56	-		

Mounting Pad Layout



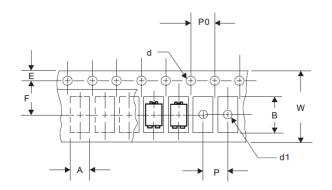
Part Numbering and Marking System



Packing Options

Part Number Marking		Packing Mode	M.O.Q
DST860S	DST860S	5000pcs / Reel	5000

Carrier Tape & Reel Specification



Symbol	Millimeters		
Syllibol	Min	Max	
Α	4.28	4.48	
В	6.80	7.00	
d	1.40	1.60	
d1	-	1.50	
E	1.65	1.85	
F	5.40	5.60	
Р	7.90	8.10	
P0	3.90	4.10	
W	11.70	12.30	